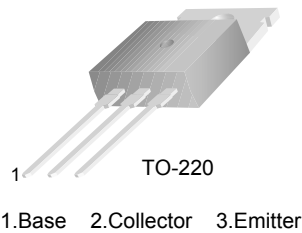


# KSD526

## NPN Epitaxial Silicon Transistor

### Power Amplifier Applications

- Complement to KSB596



### Absolute Maximum Ratings \* $T_a = 25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Value	Units
$V_{CB0}$	Collector-Base Voltage	80	V
$V_{CEO}$	Collector-Emitter Voltage	80	V
$V_{EBO}$	Emitter-Base Voltage	5	V
$I_C$	Collector Current	4	A
$I_B$	Base Current	0.4	A
$P_C$	Collector Dissipation ( $T_C=25^\circ\text{C}$ )	30	W
$T_J$	Junction Temperature	150	$^\circ\text{C}$
$T_{STG}$	Storage Temperature	-55~150	$^\circ\text{C}$

\* These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

### Electrical Characteristics $T_C = 25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Test Condition	MIN	MAX	MAX	Units
$I_{CBO}$	Collector Cut-off Current	$V_{CB} = 80\text{V}, I_E = 0$			30	$\mu\text{A}$
$I_{EBO}$	Emitter Cut-off Current	$V_{EB} = 5\text{V}, I_C = 0$			100	$\mu\text{A}$
$BV_{CEO}$	Collector-Emitter Breakdown Voltage	$I_C = 50\text{mA}, I_B = 0$	80			V
$BV_{EBO}$	Emitter-Base Breakdown Voltage	$I_E = 10\text{mA}, I_C = 0$	5			V
$h_{FE}$	DC Current Gain	$V_{CE} = 5\text{V}, I_C = 0.5\text{A}$ $V_{CE} = 5\text{V}, I_C = 3\text{A}$	40 15	50	240	
$V_{CE(sat)}$	Collector-Emitter Saturation Voltage	$I_C = 3\text{A}, I_B = 0.3\text{A}$		0.45	1.5	V
$V_{BE(on)}$	Base-Emitter On Voltage	$V_{CE} = 5\text{V}, I_C = 3\text{A}$		1	1.5	V
$f_T$	Current Gain - Bandwidth Product	$V_{CE} = 5\text{V}, I_C = 0.5\text{A}$	3	8		MHz
$C_{cb}$	Collector Output Capacitance	$V_{CB} = 10\text{V}, I_E = 0, f = 1\text{MHz}$		90		pF

### $h_{FE}$ Classification

Classification	R	O	Y
$h_{FE}$	40~80	70~140	120~240

# Typical Characteristics

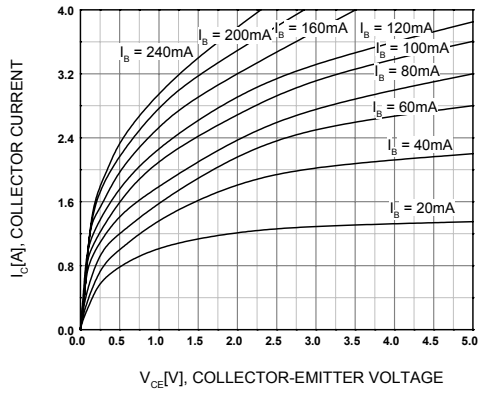


Figure 1. Static Characteristic

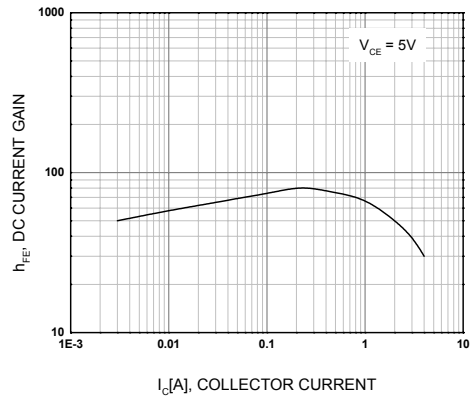


Figure 2. DC current Gain

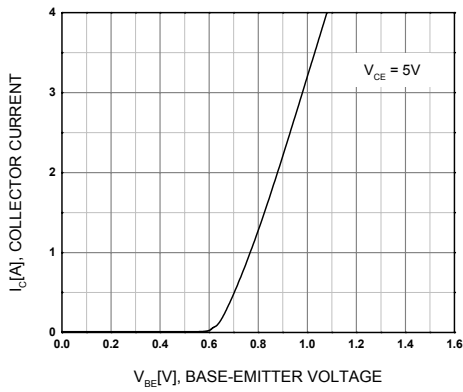


Figure 3. Base-Emitter On Voltage

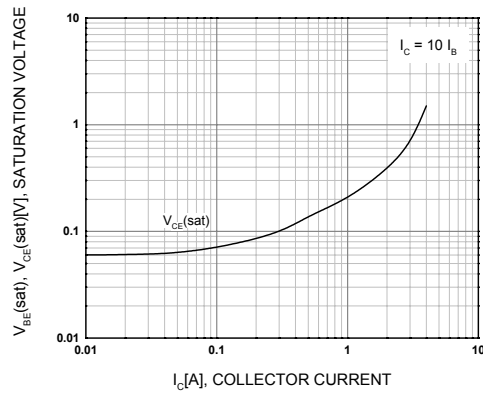


Figure 4. Collector-Emitter Saturation Voltage

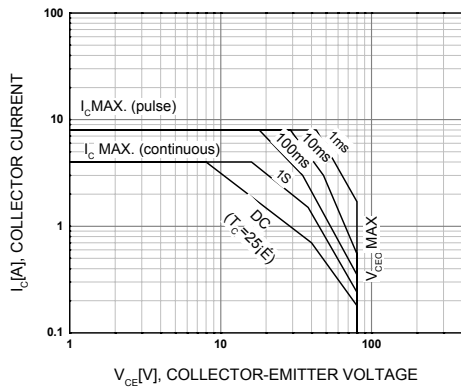


Figure 5. Safe Operating Area

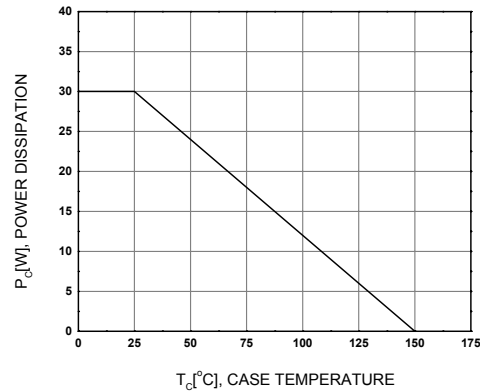
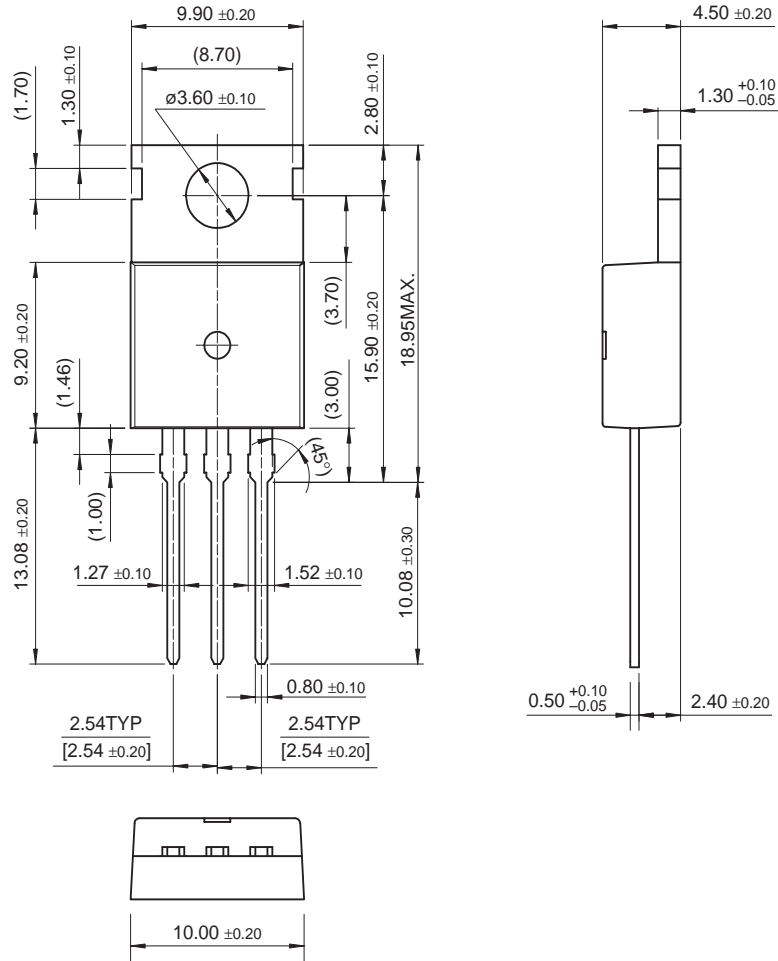


Figure 6. Power Derating

# Package Dimensions

## TO-220



Dimensions in Millimeters

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EcoSPARK™	I <sup>2</sup> C™	MSXPro™	RapidConnect™	UHC™
E <sup>2</sup> C MOS™	i-Lo™	OCX™	μSerDes™	UltraFET®
EnSigna™	ImpliedDisconnect™	OCXPro™	ScalarPump™	UniFET™
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FACT Quiet Series™		OPTOPLANAR™	SMART START™	Wire™
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